

### **FJA4210**

### **Audio Power Amplifier**

- High Current Capability : I<sub>C</sub>= -10A
- High Power Dissipation
- Wide S.O.A
- Complement to FJA4310



## **PNP Epitaxial Silicon Transistor**

## Absolute Maximum Ratings $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Value	Units	
V <sub>CBO</sub>	Collector-Base Voltage	-200	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	-140	V	
V <sub>EBO</sub>	Emitter-Base Voltage	-6	V	
Ic	Collector Current (DC)	-10	Α	
I <sub>B</sub>	Base Current (DC)	-1.5	Α	
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	100	W	
TJ	Junction Temperature	150	°C	
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C	

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

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Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C=-5$ mA, $I_E=0$	-200			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =-50mA, R <sub>BE</sub> =∞	-140			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E$ =-5mA, $I_C$ =0	-6			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =-200V, I <sub>E</sub> =0			-10	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB}$ =-6V, $I_{C}$ =0			-10	μΑ
h <sub>FE</sub>	* DC Current Gain	$V_{CE}$ =-4V, $I_{C}$ =-3A	50		180	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =-5A, I <sub>B</sub> =-0.5A			-0.5	V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =-10V, f=1MHz		400		pF
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =-5V, I <sub>C</sub> =-1A		30		MHz

<sup>\*</sup> Pulse Test : PW=20µs

## $h_{\text{FE}}$ Classification

Classification	R	0	Y	
h <sub>FE</sub>	50 ~ 100	70 ~ 140	90 ~ 180	

# **Typical Characteristics**

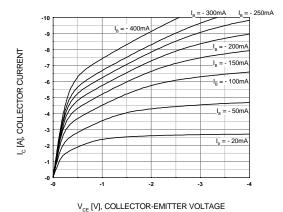


Figure 1. Static Characterstic

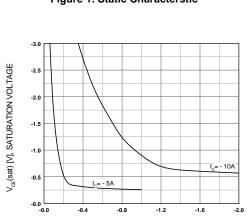


Figure 3.  $V_{CE}(sat)$  vs.  $I_{B}$  Characteristics

 ${\rm I_{\rm B}}$  [A], BASE CURRENT

-1.2

-1.6

-2.0

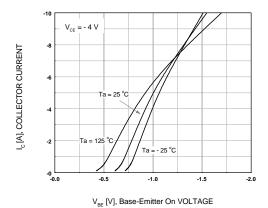


Figure 5. Base-Emitter On Voltage

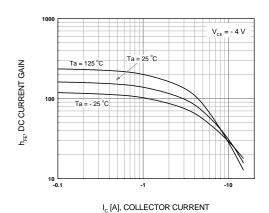


Figure 2. DC current Gain

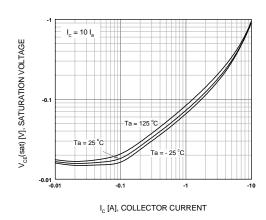
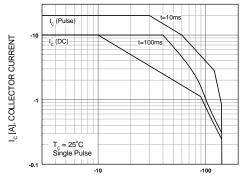


Figure 4. Collector-Emitter Saturation Voltage



 $V_{\rm CE}$  [V], COLLECTOR-EMITTER VOLTAGE

Figure 6. Forward Bias Safe Operating Area

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# Typical Characteristics (Continued)

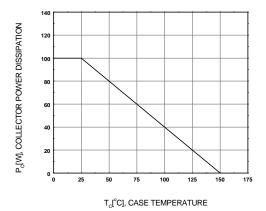
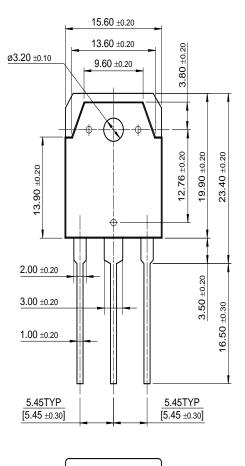
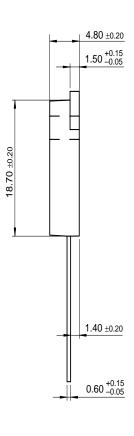


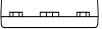
Figure 7. Power Derating

## **Package Demensions**

## TO-3P







Dimensions in Millimeters

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$CROSSVOLT^{TM}$	GTO™	$POP^{\mathsf{TM}}$	SuperSOT™-3	
DOME™	HiSeC™	Power247™	SuperSOT™-6	
EcoSPARK™	I <sup>2</sup> C™	PowerTrench <sup>®</sup>	SuperSOT™-8	
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EnSigna™	LittleFET™	QS™	TinyLogic™	
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